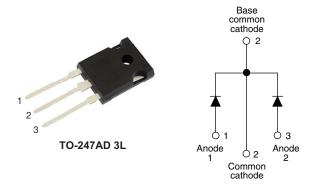


COMPLIANT

HALOGEN FREE

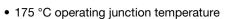
# Ultrafast Soft Recovery Diode, 2 x 30 A FRED Pt® Gen 4

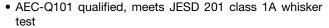


PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	2 x 30 A					
$V_{R}$	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.19 V					
t <sub>rr</sub> typ.	See Recovery table					
T <sub>J</sub> max.	175 °C					
Package	TO-247AD 3L					
Circuit configuration	Common cathode					

#### **FEATURES**

- Gen 4 FRED Pt® technology
- Low I<sub>RRM</sub> and reverse recovery charge
- Very low forward voltage drop
- Polyimide passivated chip for high reliability standard





 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **DESCRIPTION**

Gen 4 Fred technology, state of the art, ultralow  $V_F$ , soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	$V_{RRM}$		600	V			
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 131 °C	30	۸			
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave	240	А			
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	L TEST CONDITIONS		TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_{R}$	I <sub>R</sub> = 100 μA	600	-	-		
		I <sub>F</sub> = 30 A	-	1.36	1.6	V	
	V <sub>F</sub>	I <sub>F</sub> = 60 A	-	1.6	-		
Forward voltage		I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.23	-		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 125 °C	-	1.5	-		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.19	1.35		
		I <sub>F</sub> = 60 A, T <sub>J</sub> = 150 °C	-	1.48	-		
Deverage leakage average	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	50		
Reverse leakage current		T <sub>J</sub> = 125 °C, V <sub>R</sub> = V <sub>R</sub> rated	-	-	500	μA	
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	18.3	-	pF	



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST C	TYP.	MAX.	UNITS			
Reverse recovery time		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	65	-	ns	
	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	90	-		
Dook receivent ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	18	-	A	
Peak recovery current		T <sub>J</sub> = 125 °C		-	32	-		
Reverse recovery charge	0	T <sub>J</sub> = 25 °C		-	850	-	nC	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1850	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	1	°C/W	
Thermal resistance, case to heat sink	R <sub>thCS</sub>		-	0.4	-		
Weight			-	6.0	-	g	
weight			-	0.21	-	oz.	
Mounting torque			6.0	_	12	kgf · cm	
Wounting torque			(5)	_	(10)	(lbf · in)	
Marking device		Case style TO-247AD 3L	C4PU3006LH				

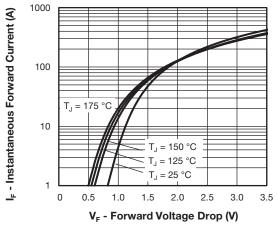


Fig. 1 - Typical Forward Voltage Drop Characteristics

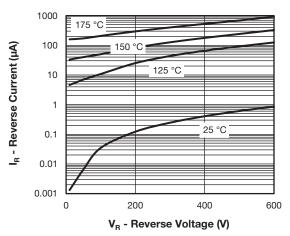


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

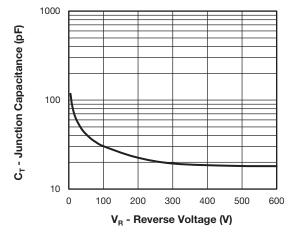


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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## Vishay Semiconductors

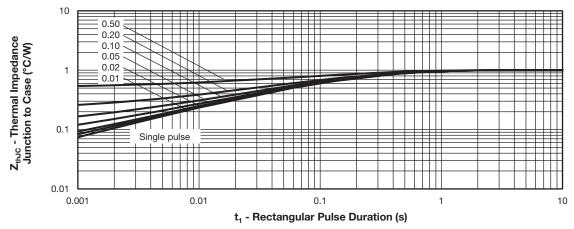


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

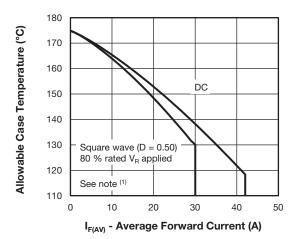


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

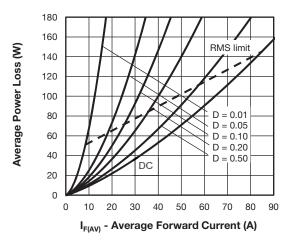


Fig. 6 - Forward Power Loss Characteristics

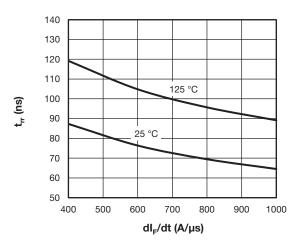


Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

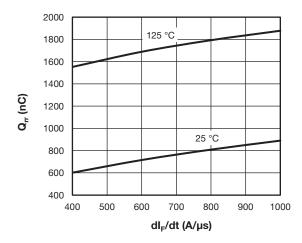


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see Fig.5)} \\ P_{dREV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_R = \text{rated } V_R \\ \end{array}$ 

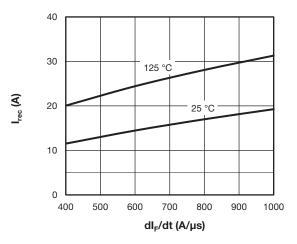
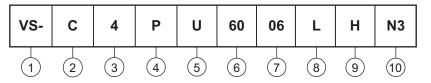


Fig. 9 - Typical Reverse Current vs. dl<sub>F</sub>/dt

#### **ORDERING INFORMATION TABLE**

**Device code** 



- 1 Vishay Semiconductors product
- 2 Circuit configuration:

C = common diode

- FRED Pt Gen 4
- P = TO-247 package
- **5** Process type:

U = ultrafast recovery

- 6 Current rating (60 = 2 x 30 A)
- 7 Voltage rating (06 = 600 V)
- 8 Package: L = long lead
- 9 H = AEC-Q101 qualified
- 10 Environmental digit:

N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING D							
VS-C4PU6006LHN3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626			
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007			



### **TO-247AD 3L**

#### **DIMENSIONS** in millimeters and inches



View B

	MILLIMETERS INCHES					
SYMBOL	IVIILLIIV	IETEKS	INC	NOTES		
01111202	MIN.	MAX.	MIN.	MAX.		
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.34	0.065	0.092		
b4	2.59	3.43	0.102	0.135		
b5	2.59	3.38	0.102	0.133		
С	0.38	0.89	0.015	0.035		
c1	0.38	0.84	0.015	0.033		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	

Section C - C, D - D, E - E

SYMBOL	MILLIN	MILLIMETERS		INCHES		
OTIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØΚ	0.2	0.254		0.010		
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217	BSC		

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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